

International
IR Rectifier

ST700C..L SERIES

PHASE CONTROL THYRISTORS

Hockey Puk Version

910A

Features

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case TO-200AC (B-PUK)

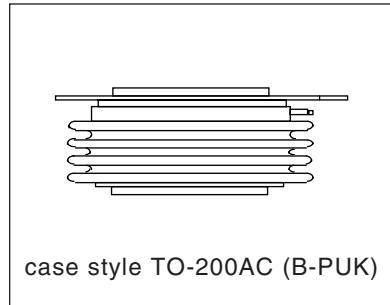
Typical Applications

- DC motor control
- Controlled DC power supplies
- AC controllers

Major Ratings and Characteristics

Parameters	ST700C..L	Units
$I_{T(AV)}$	910	A
@ T_{hs}	55	°C
$I_{T(RMS)}$	1857	A
@ T_{hs}	25	°C
I_{TSM}	15700	A
@ 60Hz	16400	A
I^2t	1232	KA ² s
@ 60Hz	1125	KA ² s
V_{DRM}/V_{RRM}	1200 to 2000	V
t_q typical	150	μs
T_J	- 40 to 125	°C

case style TO-200AC (B-PUK)



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Bulletin I25190 rev. D 04/00

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ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{DRM}/V_{RRM} , max. repetitive peak and off-state voltage V	V_{RSM} , maximum non-repetitive peak voltage V	I_{DRM}/I_{RRM} max. @ $T_J = T_{J\max}$ mA
ST700C..L	12	1200	1300	80
	16	1600	1700	
	18	1800	1900	
	20	2000	2100	

On-state Conduction

Parameter	ST700C..L	Units	Conditions
$I_{T(AV)}$ Max. average on-state current @ Heatsink temperature	910 (355)	A	180° conduction, half sine wave
	55 (85)	°C	double side (single side) cooled
$I_{T(RMS)}$ Max. RMS on-state current	1857	A	DC @ 25°C heatsink temperature double side cooled
I_{TSM} Max. peak, one-cycle non-repetitive surge current	15700		$t = 10\text{ms}$ No voltage reapplied
	16400		$t = 8.3\text{ms}$
	13200		$t = 10\text{ms}$ 100% V_{RRM} reapplied
	13800		$t = 8.3\text{ms}$ reapplied
I^2t Maximum I^2t for fusing	1232	KA ² s	Sinusoidal half wave, Initial $T_J = T_{J\max}$.
	1125		
	871		
	795		
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	12321	KA ² /s	$t = 0.1$ to 10ms, no voltage reapplied
$V_{T(TO)1}$ Low level value of threshold voltage	1.00	V	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_{J\max}$.
$V_{T(TO)2}$ High level value of threshold voltage	1.13		$(I > \pi \times I_{T(AV)})$, $T_J = T_{J\max}$.
r_{t1} Low level value of on-state slope resistance	0.40	mΩ	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_{J\max}$.
r_{t2} High level value of on-state slope resistance	0.35		$(I > \pi \times I_{T(AV)})$, $T_J = T_{J\max}$.
V_{TM} Max. on-state voltage	1.80	V	$I_{pk} = 2000\text{A}$, $T_J = T_{J\max}$, $t_p = 10\text{ms}$ sine pulse
I_H Maximum holding current	600	mA	$T_J = 25^\circ\text{C}$, anode supply 12V resistive load
I_L Typical latching current	1000		

Switching

Parameter	ST700C..L	Units	Conditions
di/dt	Max. non-repetitive rate of rise of turned-on current	1000	A/μs
t_d	Typical delay time	1.0	μs
t_q	Typical turn-off time	150	$I_{TM} = 750A, T_J = T_J \text{ max, } di/dt = 60A/\mu\text{s, } V_R = 50V$ $dv/dt = 20V/\mu\text{s, Gate } 0V \text{ to } 100\Omega, t_p = 500\mu\text{s}$

Blocking

Parameter	ST700C..L	Units	Conditions
dv/dt	Maximum critical rate of rise of off-state voltage	500	V/μs
I_{DRM}	Max. peak reverse and off-state leakage current	80	mA

Triggering

Parameter	ST700C..L	Units	Conditions
P_{GM}	Maximum peak gate power	10.0	
$P_{G(AV)}$	Maximum average gate power	2.0	
I_{GM}	Max. peak positive gate current	3.0	A
$+V_{GM}$	Maximum peak positive gate voltage	20	
$-V_{GM}$	Maximum peak negative gate voltage	5.0	V
I_{GT}	DC gate current required to trigger	TYP. 200 100 50 MAX. - 200 - -	mA
V_{GT}	DC gate voltage required to trigger	TYP. 2.5 1.8 1.1 MAX. - 3.0 - -	V
I_{GD}	DC gate current not to trigger	10	mA
V_{GD}	DC gate voltage not to trigger	0.25	V

Conditions for triggering parameters:

- $T_J = T_J \text{ max, } t_p \leq 5\text{ms}$
- $T_J = T_J \text{ max, } f = 50\text{Hz, } d\% = 50$
- $T_J = T_J \text{ max, } t_p \leq 5\text{ms}$
- $T_J = T_J \text{ max, } t_p \leq 5\text{ms}$
- $T_J = -40^\circ\text{C}$
 $T_J = 25^\circ\text{C}$
 $T_J = 125^\circ\text{C}$
- $T_J = -40^\circ\text{C}$
 $T_J = 25^\circ\text{C}$
 $T_J = 125^\circ\text{C}$
- $T_J = T_J \text{ max}$

Notes:

- Max. required gate trigger/ current/voltage are the lowest value which will trigger all units 12V anode-to-cathode applied
- Max. gate current/voltage not to trigger is the max. value which will not trigger any unit with rated V_{DRM} anode-to-cathode applied

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Bulletin I25190 rev. D 04/00

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Thermal and Mechanical Specification

Parameter	ST700C..L	Units	Conditions
T_J	Max. operating temperature range	°C	
T_{stg}	Max. storage temperature range		
R_{thJ-hs}	Max. thermal resistance, junction to heatsink	K/W	DC operation single side cooled
	0.073 0.031		DC operation double side cooled
R_{thC-hs}	Max. thermal resistance, case to heatsink	K/W	DC operation single side cooled
	0.011 0.006		DC operation double side cooled
F	Mounting force, $\pm 10\%$	14700 (1500)	N (Kg)
wt	Approximate weight	255	g
Case style	TO - 200AC (B-PUK)	See Outline Table	

ΔR_{thJ-hs} Conduction

(The following table shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction		Rectangular conduction		Units	Conditions
	Single Side	Double Side	Single Side	Double Side		
180°	0.009	0.009	0.006	0.006	K/W	$T_J = T_{J \text{ max.}}$
120°	0.011	0.011	0.011	0.011		
90°	0.014	0.014	0.015	0.015		
60°	0.020	0.020	0.021	0.021		
30°	0.036	0.036	0.036	0.036		

Ordering Information Table

Device Code									
1	ST	70	0	C	20	L	1		
1		2	3	4	5	6	7	8	
1	- Thyristor								
2	- Essential part number								
3	- 0 = Converter grade								
4	- C = Ceramic Puk								
5	- Voltage code: Code x 100 = V_{RRM} (See Voltage Rating Table)								
6	- L = Puk Case TO-200AC (B-PUK)								
7	- 0 = Eyelet terminals (Gate and Auxiliary Cathode Unsoldered Leads)								
	1 = Fast-on terminals (Gate and Auxiliary Cathode Unsoldered Leads)								
	2 = Eyelet terminals (Gate and Auxiliary Cathode Soldered Leads)								
	3 = Fast-on terminals (Gate and Auxiliary Cathode Soldered Leads)								
8	- Critical dv/dt: None = 500V/μsec (Standard selection)								
	L = 1000V/μsec (Special selection)								

Outline Table

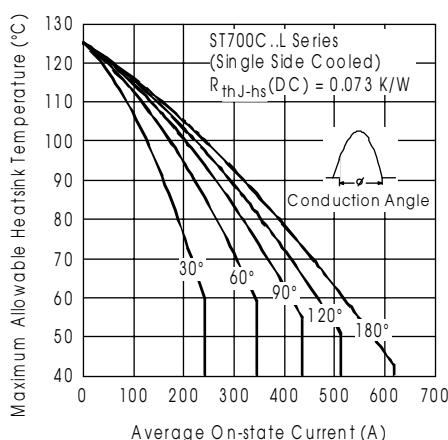
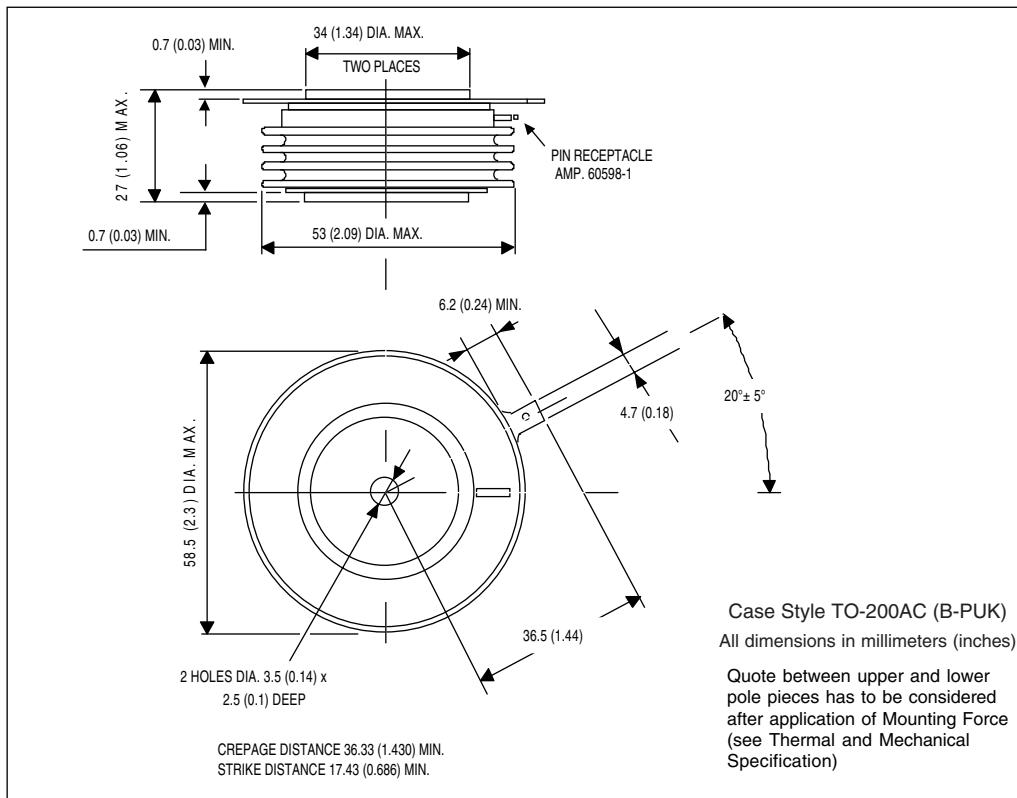


Fig. 1 - Current Ratings Characteristics

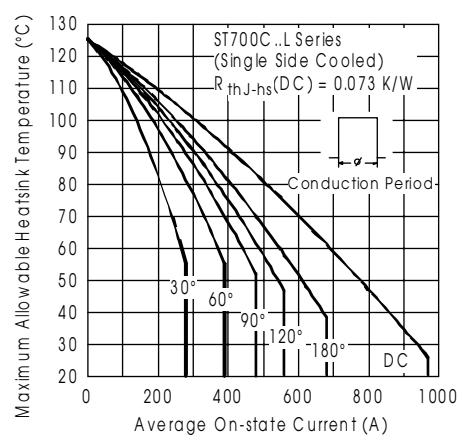


Fig. 2 - Current Ratings Characteristics

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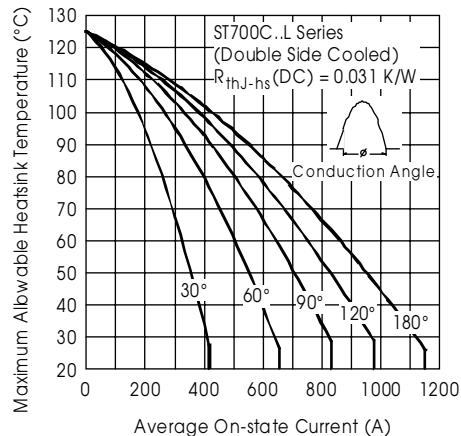


Fig. 3 - Current Ratings Characteristics

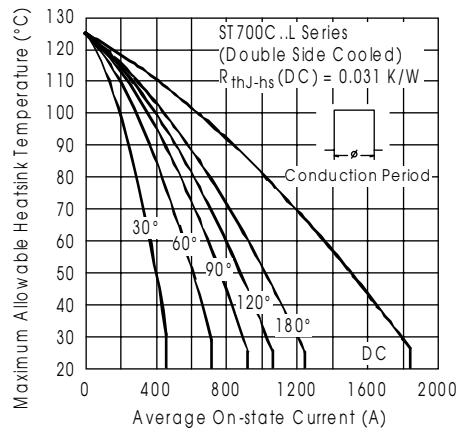


Fig. 4 - Current Ratings Characteristics

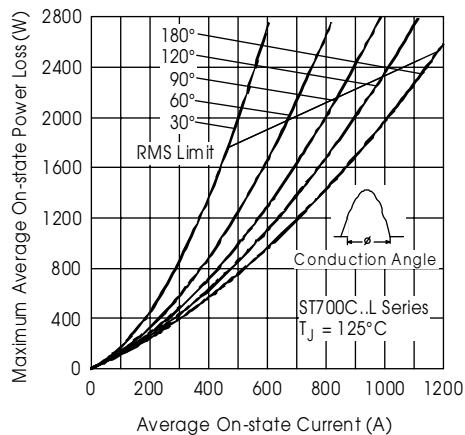


Fig. 5 - On-state Power Loss Characteristics

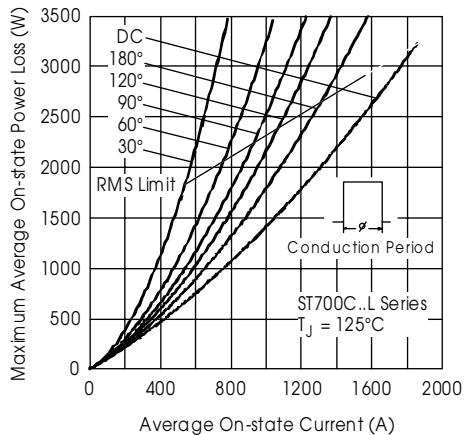


Fig. 6 - On-state Power Loss Characteristics

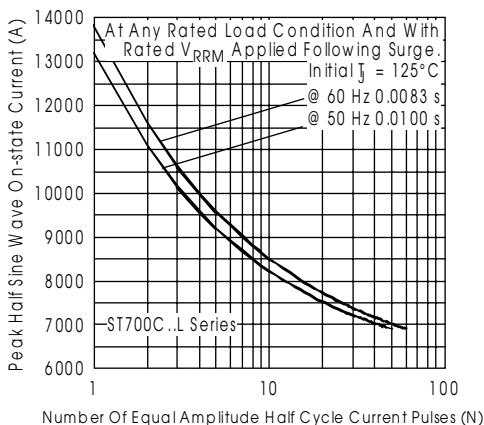


Fig. 7 - Maximum Non-Repetitive Surge Current
Single and Double Side Cooled

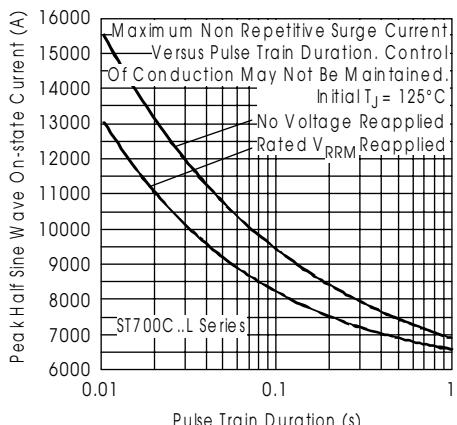


Fig. 8 - Maximum Non-Repetitive Surge Current
Single and Double Side Cooled

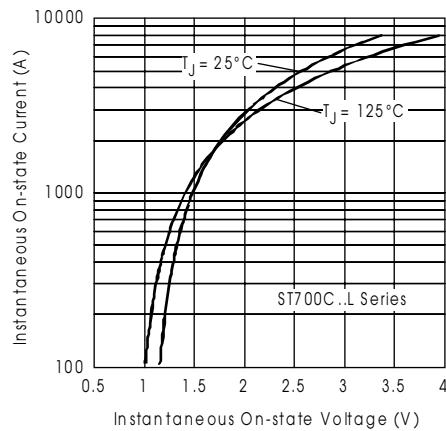


Fig. 9 - On-state Voltage Drop Characteristics

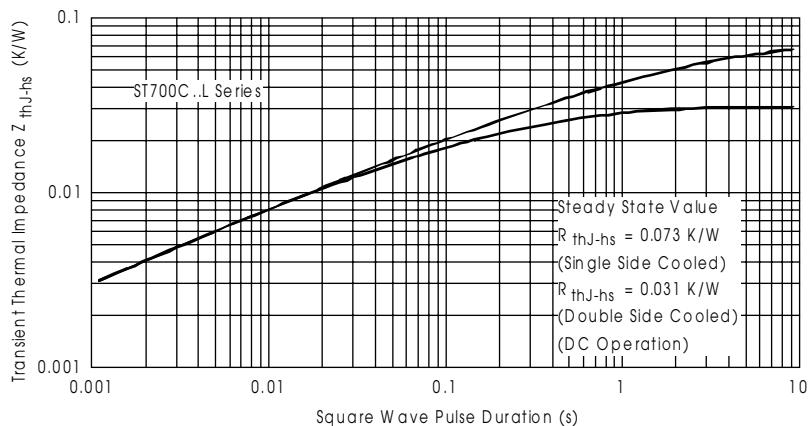


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics

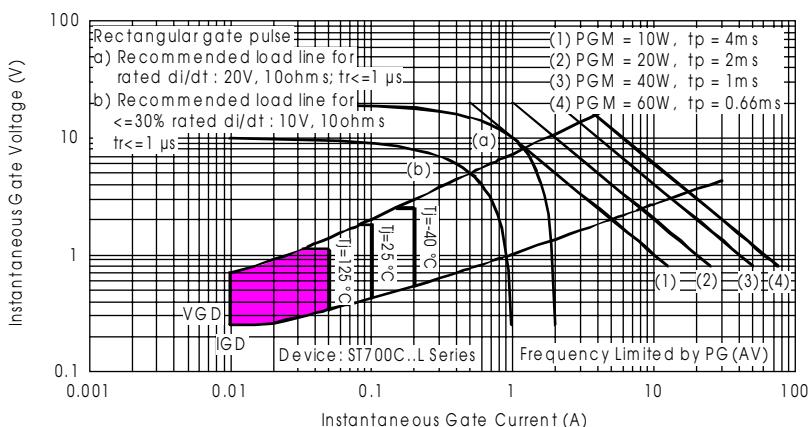


Fig. 11 - Gate Characteristics